45Ω, SPDT Analog Switch in SOT23-8

ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND.)

V+ .....-0.3V to +44.0V
V- .....-44.0V to +0.3V
V+ to V-.....-0.3V to +44.0V
All Other Pins (Note 1) .....(V- - 0.3V) to (V+ + 0.3V)
Continuous Current into any Terminal .....±10mA
Continuous Current (COM, NO, NC) .....±30mA
Peak Current (COM, NO, NC)
(pulsed at 1ms, 10% duty cycle).....±60mA

Continuous Power Dissipation (T_A = +70°C)
8-Pin SOT23 (derate 8.9mW/°C above +70°C).....714mW
Operating Temperature Range
MAX4649EKA .....-40°C to +85°C
Storage Temperature Range .....-65°C to +150°C
Junction Temperature.....+150°C
Lead Temperature (soldering, 10s) .....+300°C

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual ±15V Supplies

(V+ = +15V, V- = -15V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T_A	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}			V-		V+	V
On-Resistance	R_{ON}	I_{COM} = 1mA; V_{NO} or V_{NC} = ±10V	+25°C		33	45	Ω
			T_{MIN} to T_{MAX}			60	
On-Resistance Matching Between Channels	ΔR_{ON}	I_{COM} = 1mA; V_{NO} or V_{NC} = ±10V	+25°C		0.6	5	Ω
			T_{MIN} to T_{MAX}			6	
On-Resistance Flatness (Note 4)	$R_{FLAT (ON)}$	I_{COM} = 1mA; V_{NO} or V_{NC} = +5V, 0, -5V	+25°C		1.5	7	Ω
			T_{MIN} to T_{MAX}			10	
NO or NC Off-Leakage Current	$I_{NO(OFF)}$ or $I_{NC(OFF)}$	V_{COM} = -14V, +14V; V_{NO} or V_{NC} = +14V, -14V	+25°C	-2	0.01	2	nA
			T_{MIN} to T_{MAX}	-10		10	
COM On-Leakage Current	$I_{COM(ON)}$	V_{COM} = +14V, -14V; V_{NO} or V_{NC} = +14V, -14V or floating	+25°C	-4		4	nA
			T_{MIN} to T_{MAX}	-20		20	
DIGITAL I/O							
Input Logic High Voltage	V_{IH}			2.4			V
Input Logic Low Voltage	V_{IL}					0.8	V
Input Leakage	I_{IN}	V_{IN} = 0 or +5V		-1		1	µA

ELECTRICAL CHARACTERISTICS—Dual ±15V Supplies (continued)

(V+ = +15V, V- = -15V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T_A	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS							
Transition Time	t_{TRANS}	V_{NO} or V_{NC} = ±10V; R_L = 1kΩ; C_L = 35pF; Figure 2	+25°C		90	130	ns
			T_{MIN} to T_{MAX}			170	
Break-Before-Make Delay	t_D	V_{NO} or V_{NC} = ±10V; R_L = 300Ω; C_L = 35pF; Figure 3	+25°C	5	10		ns
			T_{MIN} to T_{MAX}	2			
Charge Injection	Q	V_{GEN} = 0; R_{GEN} = 0; C_L = 1nF; Figure 4			2		pC
Off-Isolation	V_{ISO}	f = 1MHz, R_L = 50Ω, C_L = 5pF, V_{COM} = $1V_{RMS}$; Figure 5			92		dB
Crosstalk		f = 1MHz, R_L = 50Ω, C_L = 5pF; Figure 6			92		
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, R_L = 600Ω, $5V_{RMS}$			0.015		%
V_{NO} or V_{NC} Off-Capacitance	$C_{NO(OFF)}$, $C_{NC(OFF)}$	f = 1MHz; Figure 7			6		pF
COM On-Capacitance	$C_{COM(ON)}$	f = 1MHz; Figure 8			17		pF
POWER SUPPLY							
Power-Supply Range				±4.5		±20	V
Positive Supply Current	I+	V_{IN} = 5V	+25°C		38	75	µA
			T_{MIN} to T_{MAX}			100	
		V_{IN} = 0 or V+	+25°C		0.01	1	
			T_{MIN} to T_{MAX}			10	
Negative Supply Current	I-	V_{IN} = 0 or 5V	+25°C		0.01	1	µA
			T_{MIN} to T_{MAX}			10	

45Ω, SPDT Analog Switch in SOT23-8

ELECTRICAL CHARACTERISTICS—Single +12V Supply

(V+ = +12V, V- = 0, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	T_A	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}			0		V+	V
On-Resistance	R_{ON}	I_{COM} = 1mA; V_{NO} or V_{NC} = +10V	+25°C		68	90	Ω
			T_{MIN} to T_{MAX}			115	
On-Resistance Matching Between Channels	ΔR_{ON}	I_{COM} = 1mA; V_{NO} or V_{NC} = +10V	+25°C		0.7	6	Ω
			T_{MIN} to T_{MAX}			7	
On-Resistance Flatness (Note 4)	$R_{FLAT (ON)}$	I_{COM} = 1mA; V_{NO} or V_{NC} = +2V, +6V, +10V	+25°C		9	17	Ω
			T_{MIN} to T_{MAX}			23	
DYNAMIC							
Transition Time	t_{TRANS}	V_{NO} or V_{NC} = 0, 10V or 10V, 0; R_L = 1kΩ; C_L = 35pF; Figure 2	+25°C		116	165	ns
			T_{MIN} to T_{MAX}			200	
Break-Before-Make Delay	t_D	V_{NO} or V_{NC} = +10V; R_L = 300Ω; C_L = 35pF; Figure 3	+25°C	1	36		ns
			T_{MIN} to T_{MAX}	1			
Charge Injection	Q	V_{GEN} = 0; R_{GEN} = 0; C_L = 1nF; Figure 4	+25°C		1		pC
POWER SUPPLY							
Power Supply Range				9		36	V
Positive Supply Current	I+	V_{IN} = +5V	+25°C		22	40	µA
			T_{MIN} to T_{MAX}			50	
		V_{IN} = 0 or V+	+25°C		0.01	1	
			T_{MIN} to T_{MAX}			10	

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

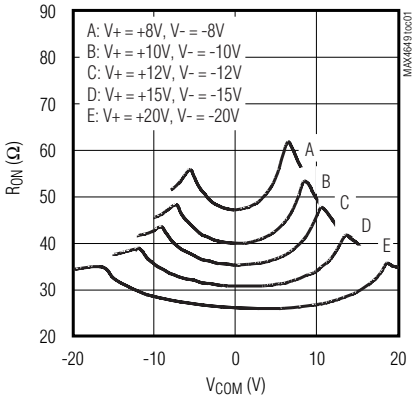
Note 3: All parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation.

Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

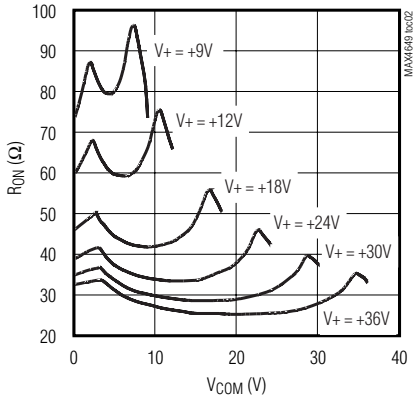
Typical Operating Characteristics

(T_A = +25°C, unless otherwise noted.)

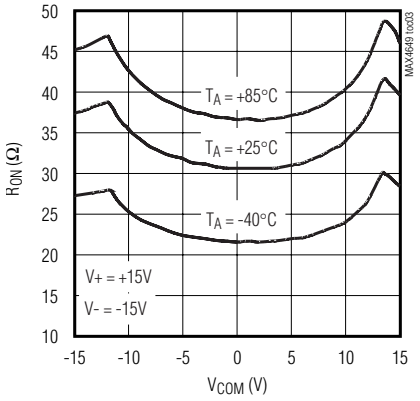
ON-RESISTANCE vs. V_{COM} (DUAL SUPPLIES)



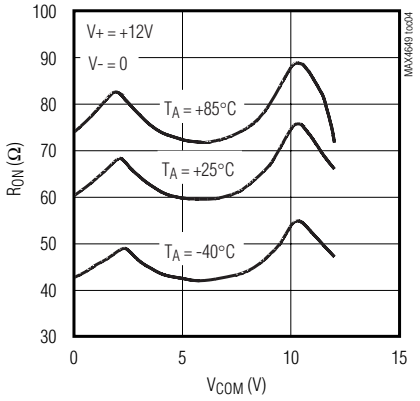
ON-RESISTANCE vs. V_{COM} (SINGLE SUPPLY)



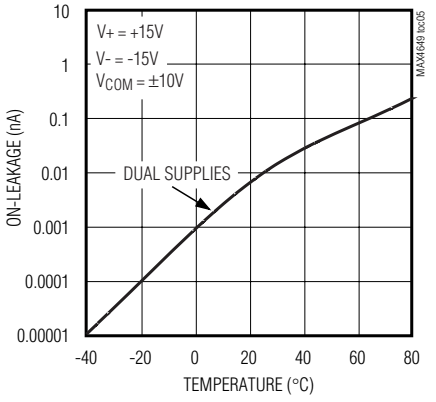
ON-RESISTANCE vs. V_{COM} AND TEMPERATURE



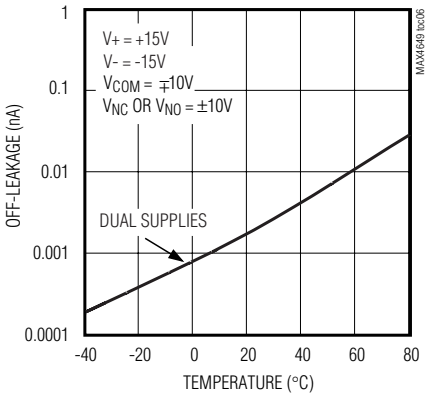
ON-RESISTANCE vs. V_{COM} AND TEMPERATURE



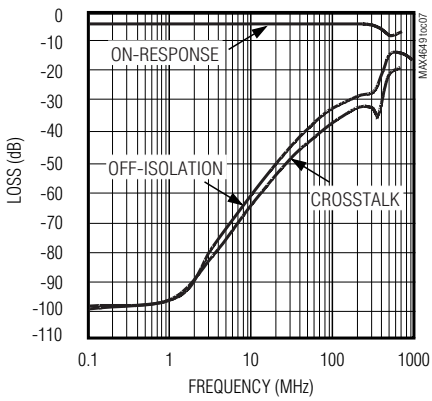
ON-LEAKAGE CURRENT vs. TEMPERATURE



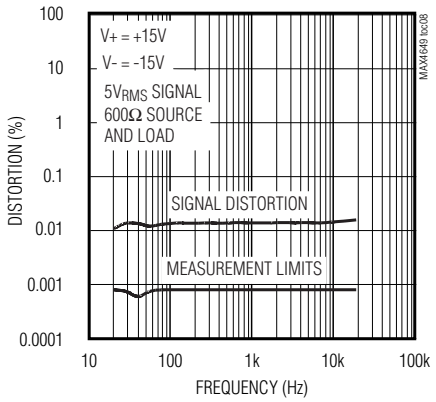
OFF-LEAKAGE CURRENT vs. TEMPERATURE



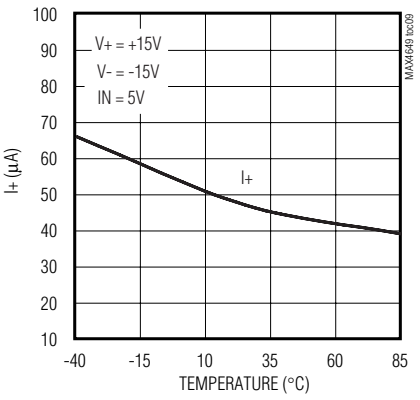
FREQUENCY RESPONSE



TOTAL HARMONIC DISTORTION vs. FREQUENCY



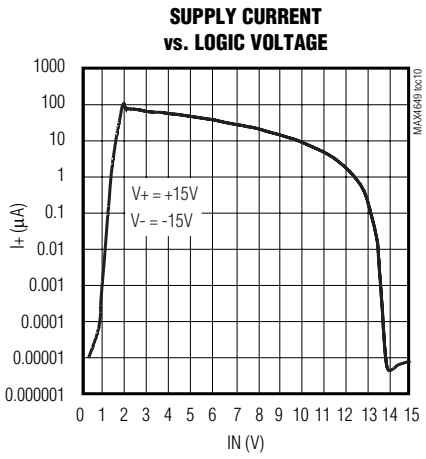
SUPPLY CURRENT vs. TEMPERATURE

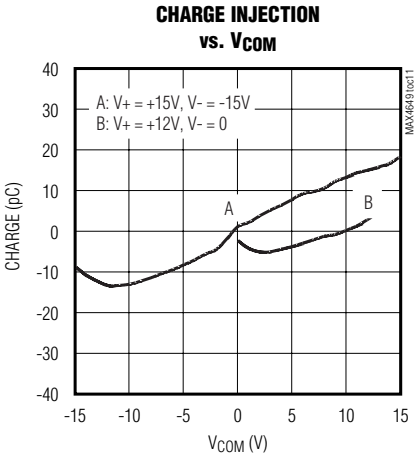


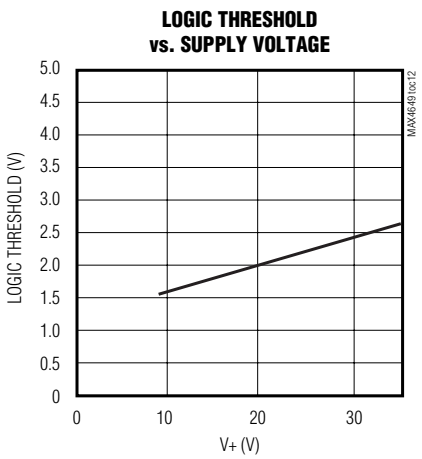
45Ω, SPDT Analog Switch in SOT23-8

Typical Operating Characteristics (continued)

(T_A = +25°C, unless otherwise noted.)







Pin Description

PIN	NAME	FUNCTION
1	COM	Analog Switch Common
2	NC	Normally Closed Switch Terminal. NC is connected to COM when IN is low.
3	GND	Ground
4	V+	Positive Supply Voltage Input
5	N.C.	No Connection
6	IN	Digital Control Input
7	V-	Negative Supply Voltage Input
8	NO	Normally Open Switch Terminal. NO is connected to COM when IN is high.

Detailed Description

The MAX4649 is a high-voltage, single-pole/double-throw (SPDT) analog switch that operates from dual ±4.5V to ±20V supplies or from a single +9V to +36V supply. The MAX4649 has one normally closed (NC) switch and one normally open (NO) switch. CMOS switch construction allows bidirectional processing of rail-to-rail analog signals.

The MAX4649 has break-before-make switching. The transition time for switching from one input to the other is typically 90ns. The off-leakage is typically less than 10pA, and on-leakage is typically less than 20pA.

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO_, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with supply pins (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the device's low switch resistance and low

leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 44V. These protection diodes are not recommended when using a single supply.

Off-Isolation at High Frequencies

In 50Ω systems, the high-frequency on-response of these parts extends from DC to above 300MHz, with a typical loss of -3.6dB. When the switch is turned off, however, it behaves like a capacitor, and off-isolation decreases with increasing frequency. This effect is more pronounced with higher source and load impedances. Above 5MHz, circuit board layout becomes critical. The graphs shown in the *Typical Operating Characteristics* were taken using a 50Ω source and load connected with BNC connectors.

Test Circuits/Timing Diagrams

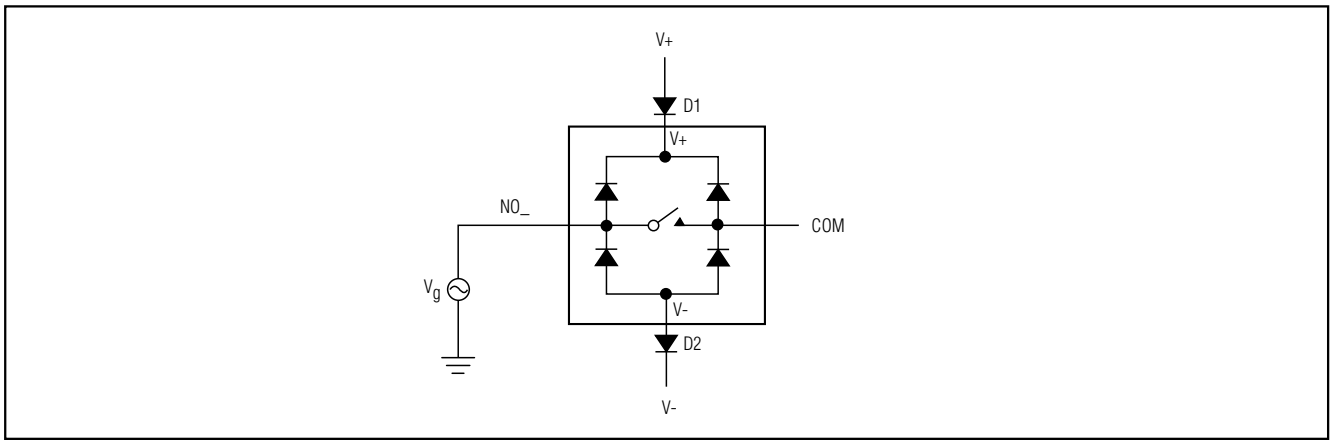


Figure 1. Overvoltage Protection

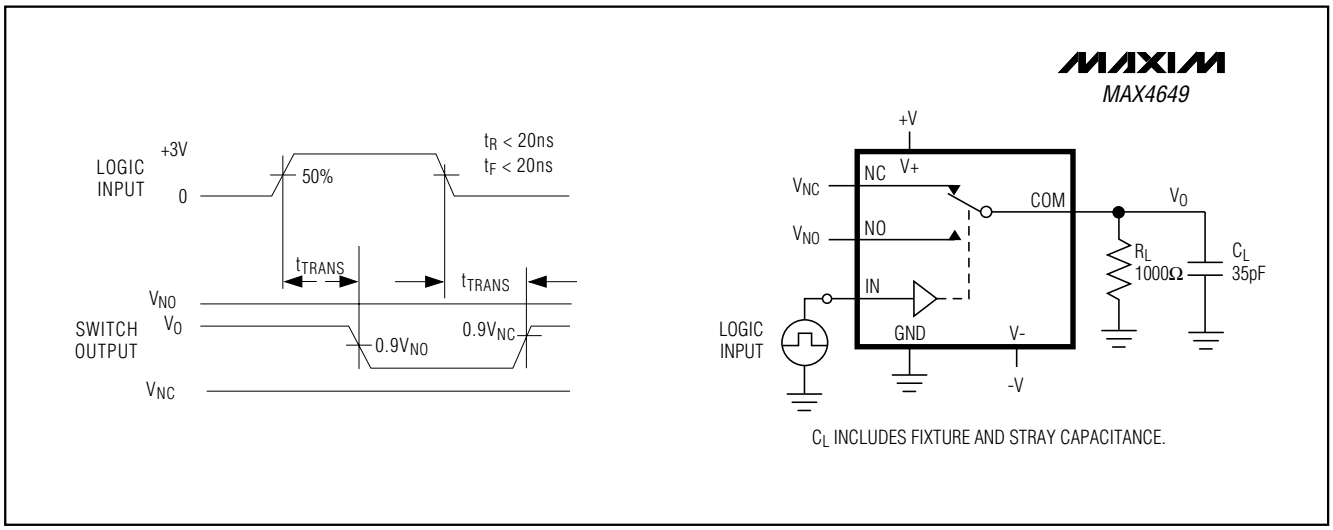


Figure 2. MAX4649 Transition Time

45Ω, SPDT Analog Switch in SOT23-8

Test Circuits/Timing Diagrams (continued)

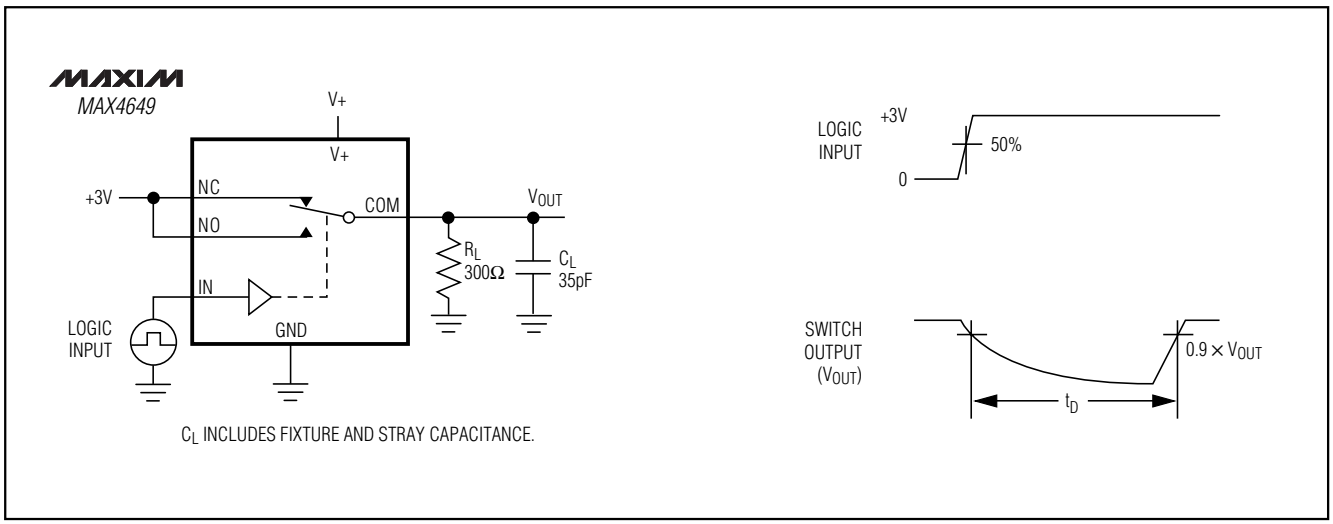


Figure 3. MAX4649 Break-Before-Make Test Circuit

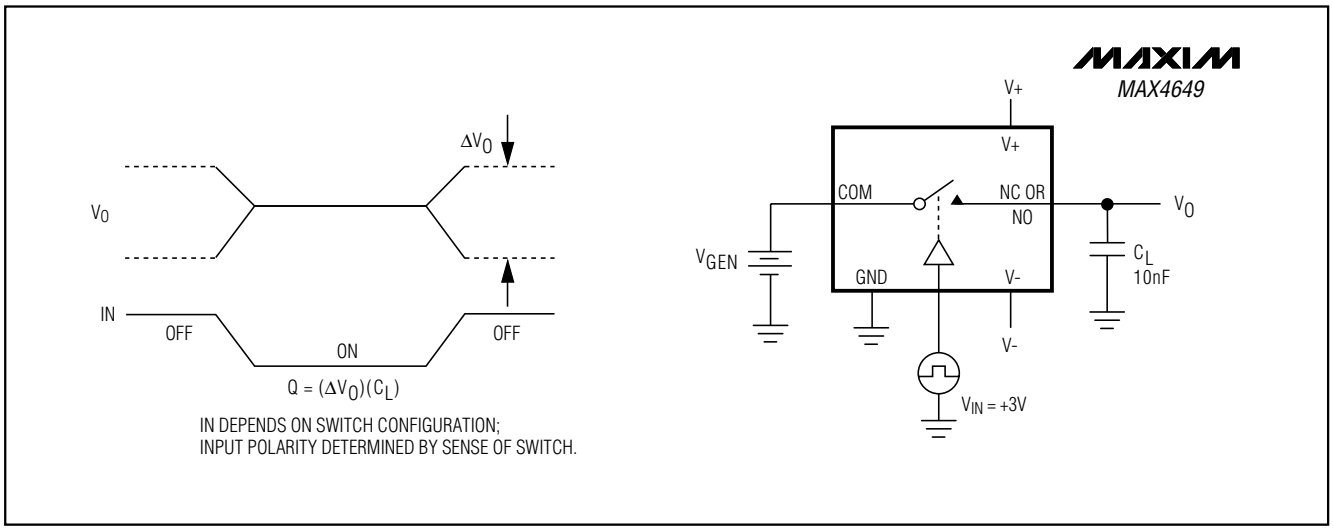


Figure 4. Charge Injection

Test Circuits/Timing Diagrams (continued)

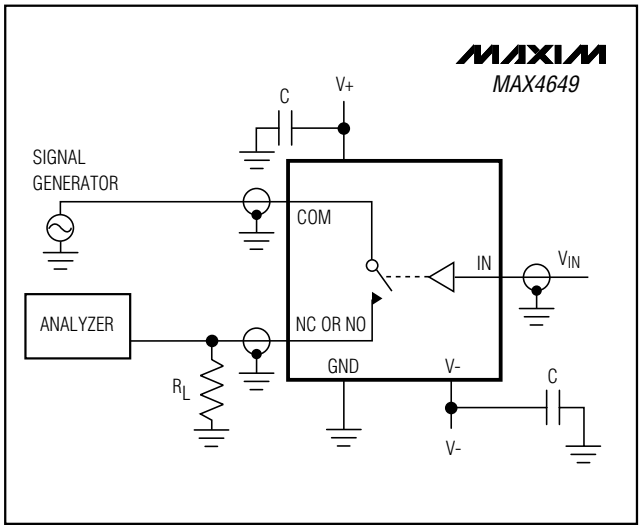


Figure 5. Off-Isolation

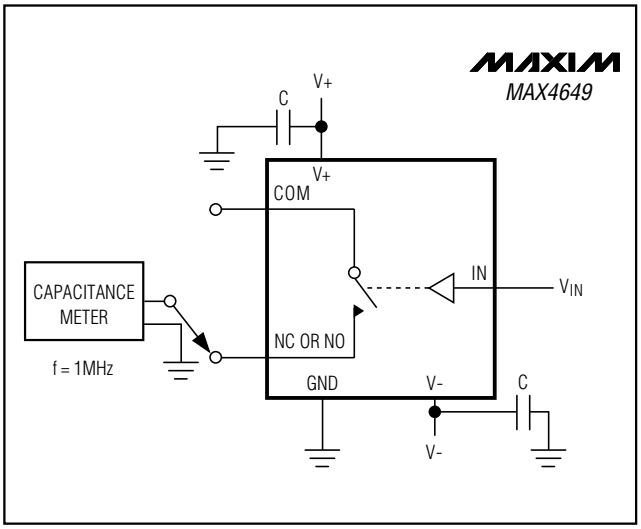


Figure 7. Channel-Off Capacitance

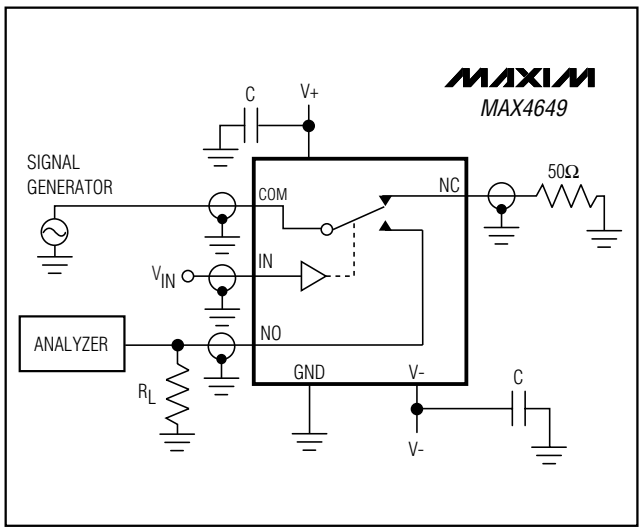


Figure 6. Crosstalk Between Switches

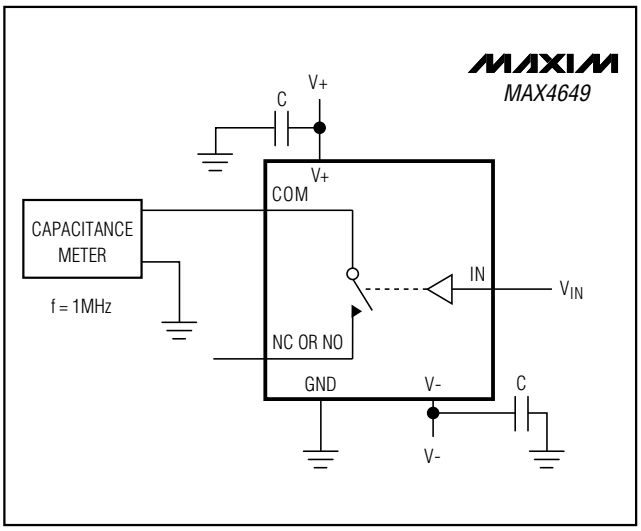


Figure 8. COM On-Capacitance

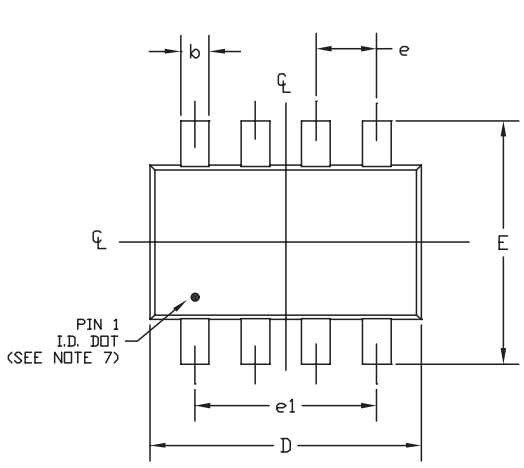
Chip Information

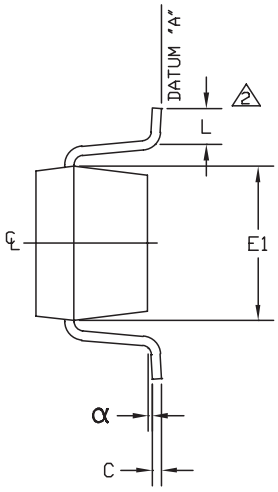
TRANSISTOR COUNT: 33
PROCESS TECHNOLOGY: CMOS

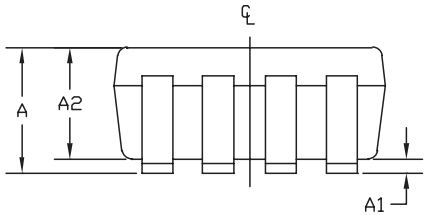
45Ω, SPDT Analog Switch in SOT23-8

Package Information

SOT23, 8L.EPS







SYMBOL	MIN	MAX
A	0.90	1.45
A1	0.00	0.15
A2	0.90	1.30
b	0.28	0.45
C	0.09	0.20
D	2.80	3.00
E	2.60	3.00
E1	1.50	1.75
L	0.10	0.60
e	0.65 ref	
e1	1.95 ref	
α	0°	10°

NOTE:
1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. FOOT LENGTH MEASURED REFERENCE TO FLAT FOOT SURFACE PARALLEL TO DATUM "A".
3. PACKAGE OUTLINE EXCLUSIVE OF MOLD FLASH & METAL BURR.
4. PACKAGE OUTLINE INCLUSIVE OF SOLDER PLATING.
5. EIAJ REF. NUMBER" SC-74 (6 LEAD VERSION)
6. COPLANARITY 4 MILS. MAX.
7. PIN 1 I.D. DOT IS 0.3 MM ø MIN. LOCATED ABOVE PIN 1.

MAXIM
PROPRIETARY INFORMATION

TITLE: PACKAGE OUTLINE, SOT 23, 8L			
APPROVAL	DOCUMENT CONTROL NO. 21-0078	REV B	1/1

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